DMA26402

Silicon PNP epitaxial planar type

For digital circuits

Features

- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

Marking Symbol: F7

Basic Part Number

Dual DRA2124E (Individual)

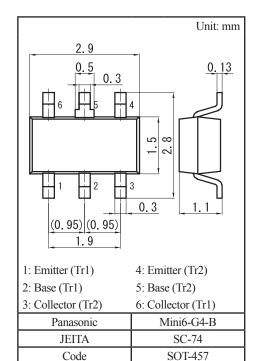
Packaging

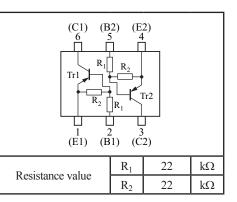
DMA264020R Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter		Symbol	Rating	Unit	
	Collector-base voltage (Emitter open)	V _{CBO}	-50	V	
Tr1 Tr2	Collector-emitter voltage (Base open)	V _{CEO}	-50	V	
	Collector current	I _C	-100	mA	
	Total power dissipation	P _T	300	mW	
Overall	Junction temperature	Tj	150	°C	
Overall	Operating ambient temperature	T _{opr}	-40 to +85	°C	
	Storage temperature	T _{stg}	-55 to +150	°C	

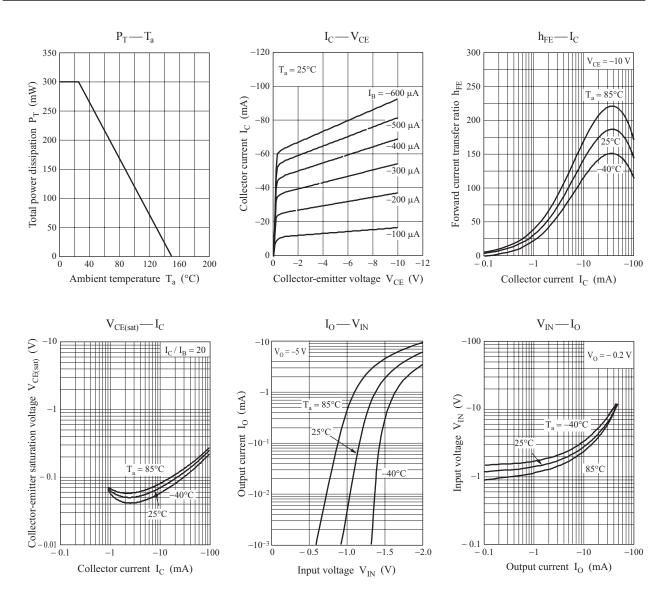
Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$



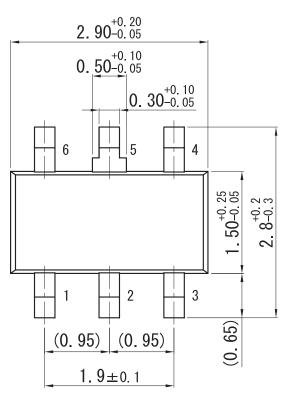


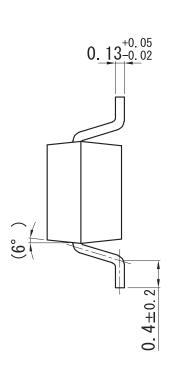
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu {\rm A}, I_{\rm E} = 0$	-50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 {\rm mA}, I_{\rm B} = 0$	-50			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{\rm CE} = -50 \text{ V}, I_{\rm B} = 0$			-0.5	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{\rm EB} = -6 V, I_{\rm C} = 0$			- 0.2	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$	60			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -0.5 \text{ mA}$			-0.25	V
Input voltage (ON)	V _{I(on)}	$V_{\rm CE} = -0.2$ V, $I_{\rm C} = -5$ mA	-2.6			V
Input voltage (OFF)	V _{I(off)}	$V_{CE} = -5 \text{ V}, I_C = -100 \mu\text{A}$			- 0.8	V
Input resistance	R ₁		-30%	22	+30%	kΩ
Resistance ratio	R ₁ / R ₂		0.8	1.0	1.2	

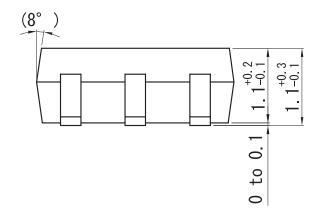
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



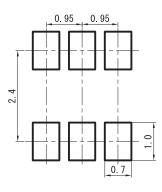
Mini6-G4-B







Land Pattern (Reference) (Unit: mm)



Ver. EED

Unit: mm

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